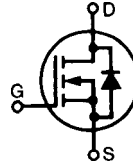


## HiPerFET™ Power MOSFETs

~~IXFH/IXFM21N50~~  
~~IXFH/IXFM/IXFT24N50~~  
IXFH/IXFT26N50

N-Channel Enhancement Mode  
High dv/dt, Low t<sub>rr</sub>, HDMOS™ Family

**Obsolete:**  
~~IXFM21N50~~  
~~IXFM24N50~~

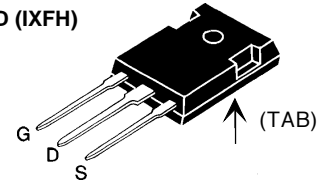


| Symbol           | Test Conditions   | Maximum Ratings             |           |
|------------------|---|-----------------------------|-----------|
| V <sub>DSS</sub> | T <sub>J</sub> = 25°C to 150°C  | 500                         | V         |
| V <sub>DGR</sub> | T <sub>J</sub> = 25°C to 150°C; R <sub>GS</sub> = 1 MΩ  | 500                         | V         |
| V <sub>GS</sub>  | Continuous  | ±20                         | V         |
| V <sub>GSM</sub> | Transient   | ±30                         | V         |
| I <sub>D25</sub> | T <sub>C</sub> = 25°C   | 21N50                       | 21 A      |
|                  |   | 24N50                       | 24 A      |
|                  |   | 26N50                       | 26 A      |
| I <sub>DM</sub>  | T <sub>C</sub> = 25°C, pulse width limited by T <sub>JM</sub>   | 21N50                       | 84 A      |
|                  |   | 24N50                       | 96 A      |
|                  |   | 26N50                       | 104 A     |
| I <sub>AR</sub>  | T <sub>C</sub> = 25°C   | 21N50                       | 21 A      |
|                  |   | 24N50                       | 24 A      |
|                  |   | 26N50                       | 26 A      |
| E <sub>AR</sub>  | T <sub>C</sub> = 25°C   | 30                          | mJ        |
| dv/dt            | I <sub>S</sub> ≤ I <sub>DM</sub> , di/dt ≤ 100 A/μs, V <sub>DD</sub> ≤ V <sub>DSS</sub> ,<br>T <sub>J</sub> ≤ 150°C, R <sub>G</sub> = 2 Ω | 5                           | V/ns      |
| P <sub>D</sub>   | T <sub>C</sub> = 25°C   | 300                         | W         |
| T <sub>J</sub>   |   | -55 ... +150                | °C        |
| T <sub>JM</sub>  |   | 150                         | °C        |
| T <sub>stg</sub> |   | -55 ... +150                | °C        |
| T <sub>L</sub>   | 1.6 mm (0.062 in.) from case for 10 s   | 300                         | °C        |
| M <sub>d</sub>   | Mounting torque   | 1.13/10                     | Nm/lb.in. |
| Weight           |   | TO-204 = 18 g, TO-247 = 6 g |           |

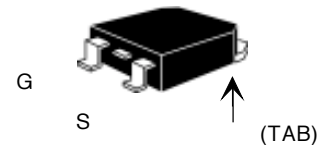
| V <sub>DSS</sub> | I <sub>D25</sub> | R <sub>DS(on)</sub> |
|------------------|------------------|---------------------|
| 500 V            | 21 A             | 0.25 Ω              |
| 500 V            | 24 A             | 0.23 Ω              |
| 500 V            | 26 A             | 0.20 Ω              |

t<sub>rr</sub> ≤ 250 ns

TO-247 AD (IXFH)

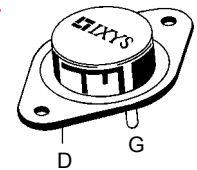


TO-268 (D3) Case Style



~~TO-204 AE (IXFM)~~

**Package not available**



G = Gate, D = Drain,  
S = Source, TAB = Drain

### Features

- International standard packages
- Low R<sub>DS(on)</sub> HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Low package inductance  
- easy to drive and to protect
- Fast intrinsic Rectifier

### Applications

- DC-DC converters
- Synchronous rectification
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control
- Temperature and lighting controls
- Low voltage relays

### Advantages

- Easy to mount with 1 screw (TO-247) (isolated mounting screw hole)
- High power surface mountable package
- High power density

| Symbol              | Test Conditions   | Characteristic Values<br>(T <sub>J</sub> = 25°C, unless otherwise specified) |      |         |
|---------------------|---|--|------|---------|
|                     |   | min.   | typ. | max.    |
| V <sub>DSS</sub>    | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA                    | 500  |      | V       |
| V <sub>GS(th)</sub> | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 4 mA         | 2  |      | V       |
| I <sub>GSS</sub>    | V <sub>GS</sub> = ±20 V <sub>DC</sub> , V <sub>DS</sub> = 0       |  |      | ±100 nA |
| I <sub>DSS</sub>    | V <sub>DS</sub> = 0.8 • V <sub>DSS</sub><br>V <sub>GS</sub> = 0 V | T <sub>J</sub> = 25°C  |      | 200 μA  |
|                     |   | T <sub>J</sub> = 125°C   |      | 1 mA    |



**IXFH21N50**  
**IXFM21N50**

**IXFH24N50**  
**IXFM24N50**  
**IXFT24N50**

**IXFH26N50**  
**IXFM26N50**  
**IXFT26N50**

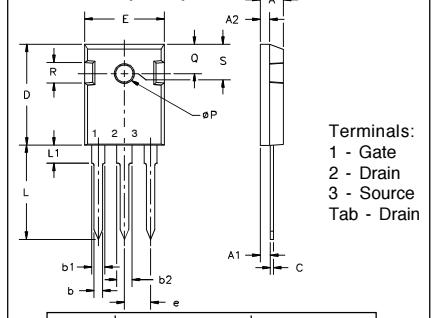
| Symbol  | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified)                                  | Characteristic Values   |      |   |
|---|--|-------------------------|------|---|
|   |  | Min.                    | Typ. | Max.  |
| $R_{DS(on)}$                                  | $V_{GS} = 10\text{ V}, I_D = 0.5 I_{D25}$<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ | 21N50<br>24N50<br>26N50 |      | 0.25 $\Omega$<br>0.23 $\Omega$<br>0.20 $\Omega$ |
| $g_{fs}$                                      | $V_{DS} = 10\text{ V}; I_D = 0.5 I_{D25}$ , pulse test   | 11                      | 21   | S   |
| $C_{iss}$<br>$C_{oss}$<br>$C_{rss}$           | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$  |                         | 4200 | pF  |
|   |  |                         | 450  | pF  |
|   |  |                         | 135  | pF  |
| $t_{d(on)}$<br>$t_r$<br>$t_{d(off)}$<br>$t_f$ | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$<br>$R_G = 2\ \Omega$ (External)              |                         | 16   | 25 ns   |
|   |  |                         | 33   | 45 ns   |
|   |  |                         | 65   | 80 ns   |
|   |  |                         | 30   | 40 ns   |
| $Q_{g(on)}$<br>$Q_{gs}$<br>$Q_{gd}$           | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$  |                         | 135  | 160 nC  |
|   |  |                         | 28   | 40 nC   |
|   |  |                         | 62   | 85 nC   |
| $R_{thJC}$<br>$R_{thCK}$                      | (TO-247 Case Style)  | 0.25                    |      | 0.42 K/W<br>K/W                                 |

**Source-Drain Diode** **Characteristic Values**  
( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

| Symbol   | Test Conditions   | Min.  | Typ.     | Max.                  |
|----------|---|---|----------|-----------------------|
| $I_S$    | $V_{GS} = 0\text{ V}$   | 21N50<br>24N50<br>26N50                               |          | 21 A<br>24 A<br>26 A  |
| $I_{SM}$ | Repetitive;<br>pulse width limited by $T_{JM}$  | 21N50<br>24N50<br>26N50                               |          | 84 A<br>96 A<br>104 A |
| $V_{SD}$ | $I_F = I_S, V_{GS} = 0\text{ V}$ ,<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |   |          | 1.5 V                 |
| $t_{rr}$ | $I_F = I_S$   | $T_J = 25^\circ\text{C}$                              |          | 250 ns                |
|          |   | $T_J = 125^\circ\text{C}$                             |          | 400 ns                |
| $Q_{RM}$ | $-di/dt = 100\text{ A}/\mu\text{s}$ ,<br>$V_R = 100\text{ V}$   | $T_J = 25^\circ\text{C}$                              | 1        | $\mu\text{C}$         |
|          |   | $T_J = 125^\circ\text{C}$                             | 2        | $\mu\text{C}$         |
| $I_{RM}$ |   | $T_J = 25^\circ\text{C}$<br>$T_J = 125^\circ\text{C}$ | 10<br>15 | A<br>A                |

Note 1: Add "S" suffix for TO-247 SMD package option (ex: IXFH24N50S)

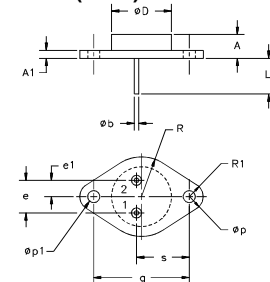
**TO-247 AD (IXFH) Outline**



Terminals:  
1 - Gate  
2 - Drain  
3 - Source  
Tab - Drain

| Dim.            | Millimeter |       | Inches |       |
|-----------------|------------|-------|--------|-------|
|                 | Min.       | Max.  | Min.   | Max.  |
| A               | 4.7        | 5.3   | .185   | .209  |
| A <sub>1</sub>  | 2.2        | 2.54  | .087   | .102  |
| A <sub>2</sub>  | 2.2        | 2.6   | .059   | .098  |
| b               | 1.0        | 1.4   | .040   | .055  |
| b <sub>1</sub>  | 1.65       | 2.13  | .065   | .084  |
| b <sub>2</sub>  | 2.87       | 3.12  | .113   | .123  |
| C               | .4         | .8    | .016   | .031  |
| D               | 20.80      | 21.46 | .819   | .845  |
| E               | 15.75      | 16.26 | .610   | .640  |
| e               | 5.20       | 5.72  | 0.205  | 0.225 |
| L               | 19.81      | 20.32 | .780   | .800  |
| L <sub>1</sub>  |            | 4.50  |        | .177  |
| $\varnothing P$ | 3.55       | 3.65  | .140   | .144  |
| Q               | 5.89       | 6.40  | 0.232  | 0.252 |
| R               | 4.32       | 5.49  | .170   | .216  |
| S               | 6.15       | BSC   | .242   | BSC   |

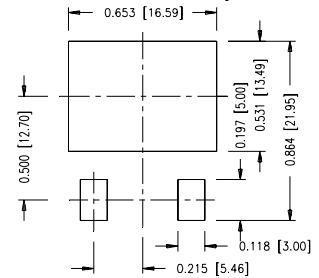
**TO-204 AE (IXFM) Outline**



Pins: 1 - Gate, 2 - Source, Case - Drain

| Dim.              | Millimeter |       | Inches    |      |
|-------------------|------------|-------|-----------|------|
|                   | Min.       | Max.  | Min.      | Max. |
| A                 | 6.4        | 11.4  | .250      | .450 |
| A <sub>1</sub>    | 1.53       | 3.42  | .060      | .135 |
| $\varnothing b$   | 1.45       | 1.60  | .057      | .063 |
| $\varnothing D$   |            | 22.22 |           | .875 |
| e                 | 10.67      | 11.17 | .420      | .440 |
| e <sub>1</sub>    | 5.21       | 5.71  | .205      | .225 |
| L                 | 11.18      | 12.19 | .440      | .480 |
| $\varnothing p$   | 3.84       | 4.19  | .151      | .165 |
| $\varnothing p_1$ | 3.84       | 4.19  | .151      | .165 |
| q                 | 30.15 BSC  |       | 1.187 BSC |      |
| R                 | 12.58      | 13.33 | .495      | .525 |
| R <sub>1</sub>    | 3.33       | 4.77  | .131      | .188 |
| s                 | 16.64      | 17.14 | .655      | .675 |

**Min. Recommended Footprint**



| SYM            | INCHES   |      | MILLIMETERS |       |
|----------------|----------|------|-------------|-------|
|                | MIN      | MAX  | MIN         | MAX   |
| A              | .193     | .201 | 4.90        | 5.10  |
| A <sub>1</sub> | .106     | .114 | 2.70        | 2.90  |
| A <sub>2</sub> | .001     | .010 | 0.02        | 0.25  |
| b              | .045     | .057 | 1.15        | 1.45  |
| b <sub>2</sub> | .075     | .083 | 1.90        | 2.10  |
| C              | .016     | .026 | 0.40        | 0.65  |
| C <sub>2</sub> | .057     | .063 | 1.45        | 1.60  |
| D              | .543     | .551 | 13.80       | 14.00 |
| D <sub>1</sub> | .488     | .500 | 12.40       | 12.70 |
| E              | .624     | .632 | 15.85       | 16.05 |
| E <sub>1</sub> | .524     | .535 | 13.30       | 13.60 |
| e              | .215 BSC |      | 5.45 BSC    |       |
| H              | .736     | .752 | 18.70       | 19.10 |
| L              | .094     | .106 | 2.40        | 2.70  |
| L <sub>1</sub> | .047     | .055 | 1.20        | 1.40  |
| L <sub>2</sub> | .039     | .045 | 1.00        | 1.15  |
| L <sub>3</sub> | .010 BSC |      | 0.25 BSC    |       |
| L <sub>4</sub> | .150     | .161 | 3.80        | 4.10  |

IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,881,106 5,017,508 5,049,961 5,187,117 5,486,715  
4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025

Fig. 1 Output Characteristics

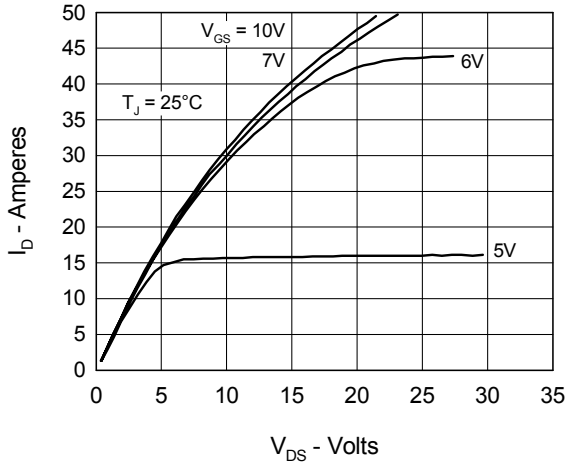


Fig. 2 Input Admittance

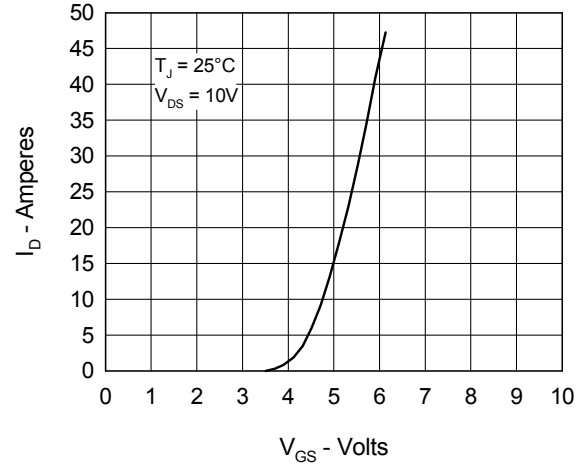


Fig. 3  $R_{DS(on)}$  vs. Drain Current

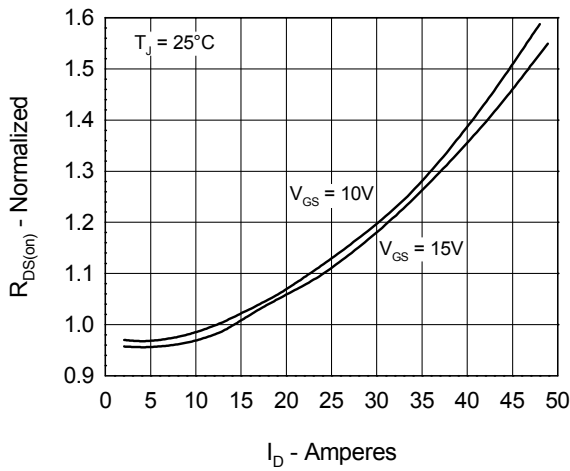


Fig. 4 Temperature Dependence of Drain to Source Resistance

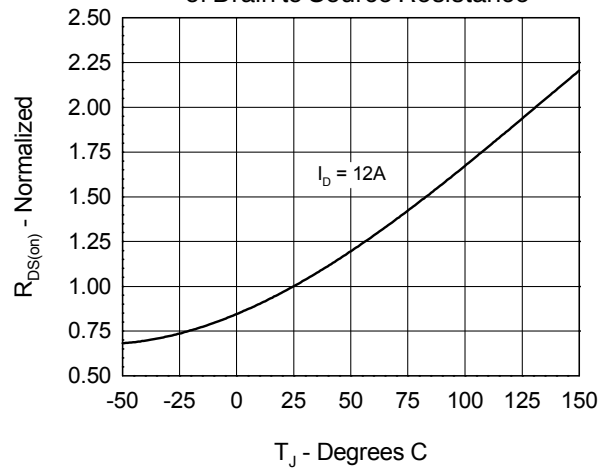


Fig. 5 Drain Current vs. Case Temperature

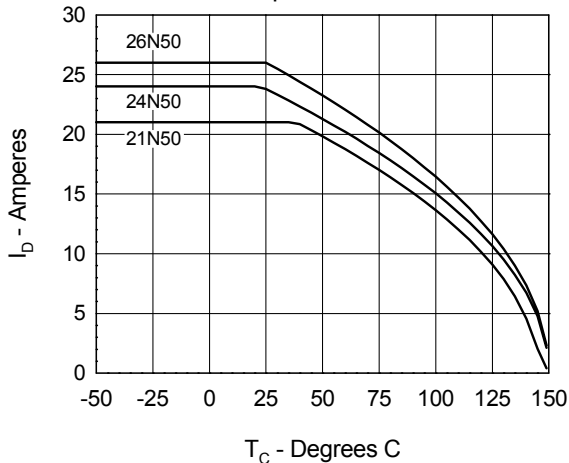


Fig. 6 Temperature Dependence of Breakdown and Threshold Voltage

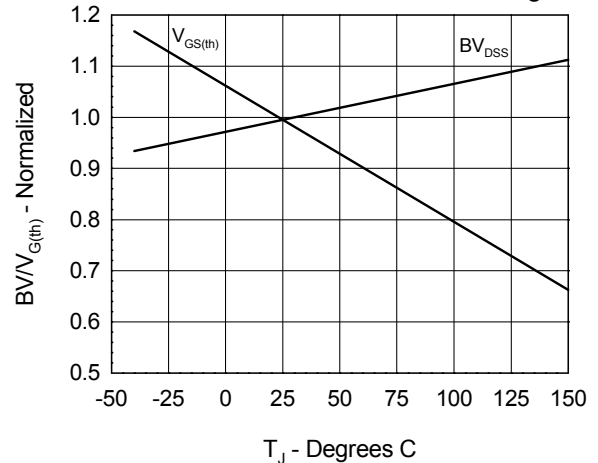


Fig.7 Gate Charge Characteristic Curve

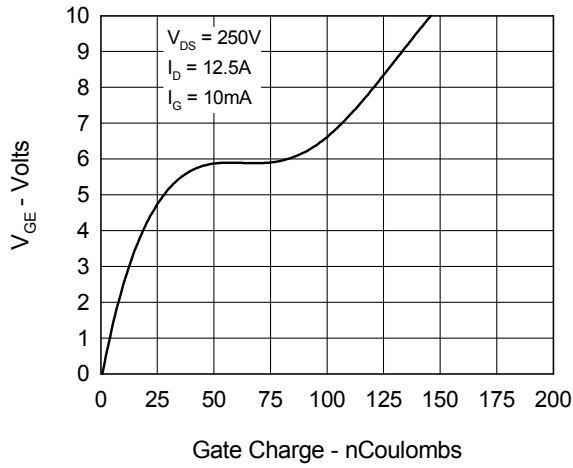


Fig.9 Capacitance Curves

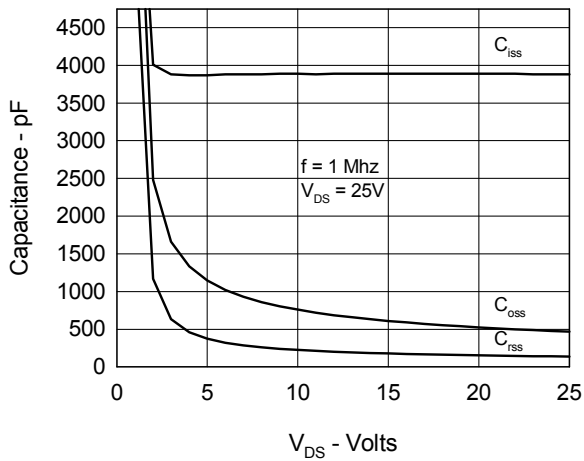


Fig.11 Transient Thermal Impedance

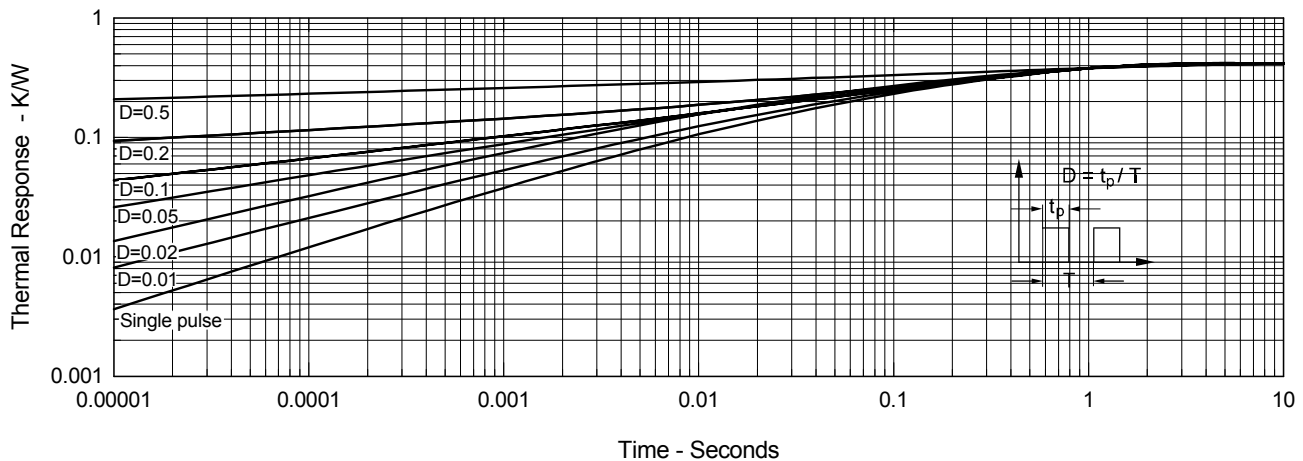


Fig.8 Forward Bias Safe Operating Area

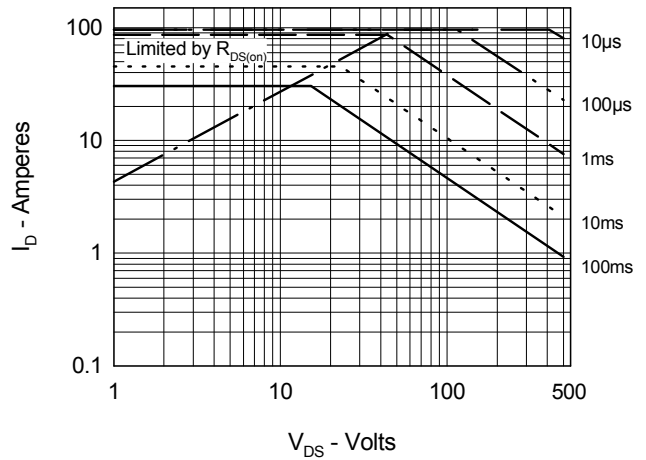
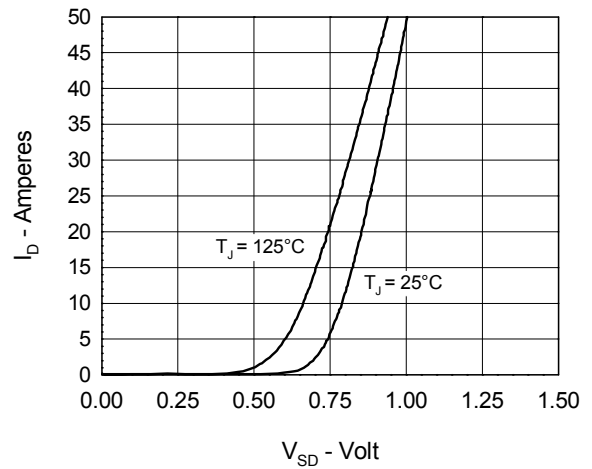


Fig.10 Source Current vs. Source to Drain Voltage





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